Ø 001

RECEIVED

CENTRAL FAX CENTER

NOV 2 4 2003

LAW OFFICES OF

McGINN & GIBB, PLLC

A PROFESSIONAL LIMITED LIABILITY COMPANY PATENTS, TRADEMARKS, COPYRIGHTS, AND INTELLECTUAL PROPERTY LAW 8321 OLD COURTHOUSE ROAD, SUITE 200

VIENNA, VIRGINIA 22182-3817 TELEPHONE: (703) 761-4100 FACSIMILE/DATA: (703) 761-2375; 761-2376

E-MAIL: MCGINNGIBB @ AOL.COM

ANNAPOLIS, MD OFFICE FREDERICK W. GIBB, III MOHAMMAD'S. RAHMANT

SEAN M. MCGINN PHILLIP E. MILLERT FREDERICK E. COOPERRIDERT PETER A. BALNAVE, Ph.D. FREDRIC J. ZIMMERMANT JAMES E. HOWARDT JAMES N. DRESSER TMEMBER OF BAR OTHER THAN VA

November 24, 2003

VIA FACSIMILE

Examiner Erik J. Kielin To:

Group Art Unit No. 2813

U.S.P.T.O.

From: Sean M. McGinn

Facsimile No.: (703) 761-2375

Facsimile No.: (703) 872-9319

Re: Enclosed Amendment Under 37 C.F.R. § 1.116

U.S. Patent Application Serial No. 09/902,483

Our Reference: YOR.129CIP

Dear Examiner Kielin:

Enclosed is an Amendment Under 37 C.F.R. § 1.116, responsive to the September 4, 2003 Office Action, which we request that you enter and which should place the abovereferenced case in condition for allowance.

Thank you in advance for your kind consideration on this case.

Very truly yours.

Sean M. McGinn

SMM:abs Enclosure

Total No. of Pages Transmitted: 32

RECEIVED CENTRAL FAX CENTER

NOV 2 4 2003

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of

Cabral et al.

Serial No.: 09/902,483

Group Art Unit: 2813

Filed: July 11, 2001

Examiner: Erik Kielin

For:

SELF-ALIGNED SILICIDE (SALICIDE) PROCESS FOR LOW RESISTIVITY

CONTACTS TO THIN FILM SILICON-ON-INSULATOR AND BULK MOSFETS

AND FOR SHALLOW JUNCTIONS

Honorable Commissioner of Patents Alexandria, VA 22313-1450 BOX AF

AMENDMENT UNDER 37 C.F.R. §1.116

Sir:

In response to the Office Action dated September 4, 2003, please amend the aboveidentified application as follows:

INTRODUCTORY COMMENTS

Amendments to the Claims are reflected in the listing of claims which begins on page 2 of this paper. No new matter has been added.

Remarks begin on page 10 of this paper.